

# AN8473SA

## Spindle motor driver IC for optical disk

### ■ Overview

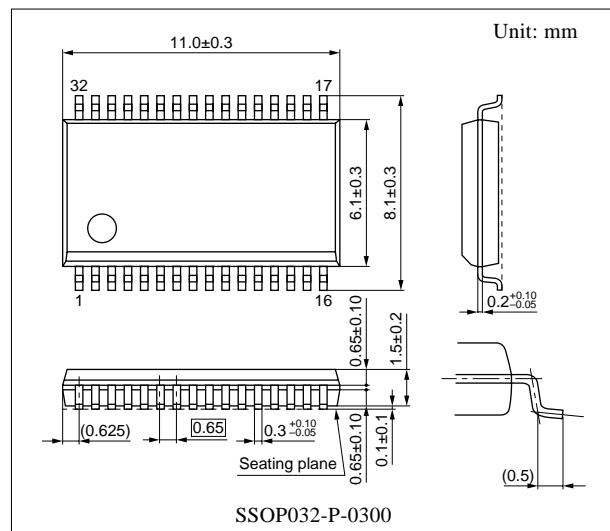
The AN8473SA is an optical disk driver IC, featuring direct PWM drive, DMOS power drive, low ON resistance of output power MOS and 120° of duty-factor.

### ■ Features

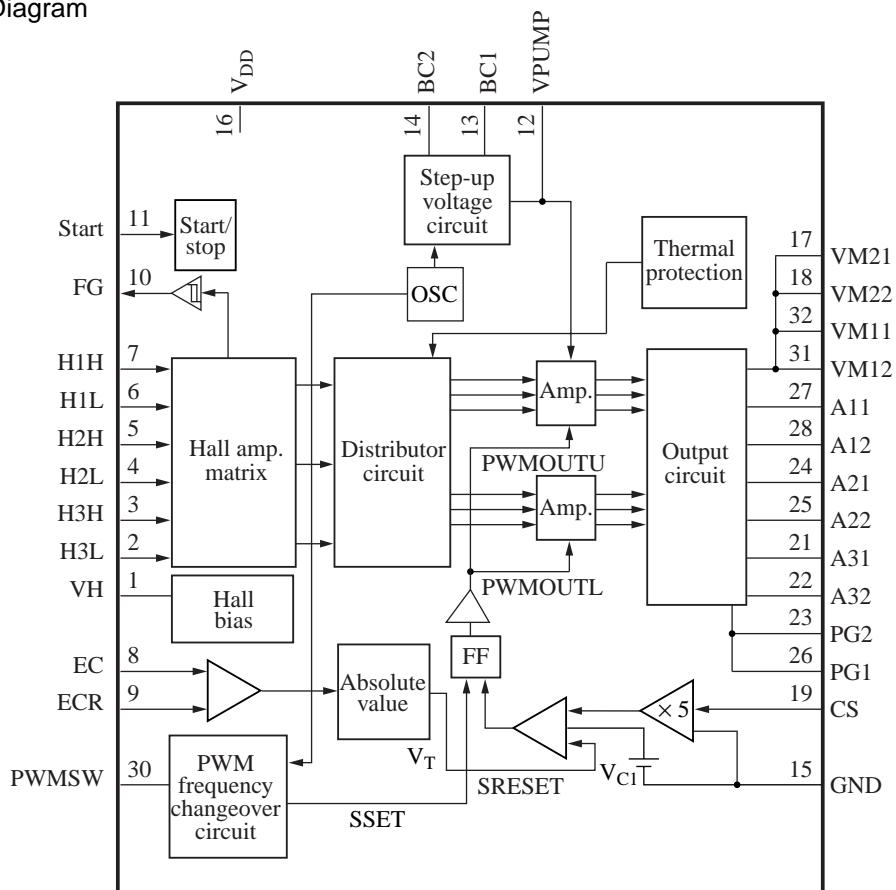
- $R_{ON} = 0.5 \Omega$  (for both upper and lower)
- 5 V single power source
- Circuit current 7 mA (including step-up circuit current)

### ■ Applications

- Optical disk



### ■ Block Diagram



## ■ Pin Descriptions

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	VH	Hall bias pin	17	VM21	Motor supply voltage pin 2
2	H3L	Hall element-3 negative input pin	18	VM22	Motor supply voltage pin 2
3	H3H	Hall element-3 positive input pin	19	CS	Current det. pin
4	H2L	Hall element-2 negative input pin	20	N.C.	N.C.
5	H2H	Hall element-2 positive input pin	21	A31	Drive output 3
6	H1L	Hall element-1 negative input pin	22	A32	Drive output 3
7	H1H	Hall element-1 positive input pin	23	PG2	Power current det. pin 2
8	EC	Torque command input pin	24	A21	Drive output 2
9	ECR	Torque command reference input pin	25	A22	Drive output 2
10	FG	FG signal output pin	26	PG1	Power current det. pin 1
11	Start	Start/stop changeover pin	27	A11	Drive output 1
12	VPUMP	Booster pin	28	A12	Drive output 1
13	BC1	Booster capacitor connection pin 1	29	N.C.	N.C.
14	BC2	Booster capacitor connection pin 2	30	PWMSW	PWM frequency changeover pin
15	GND	Ground pin	31	VM12	Motor supply voltage pin 1
16	V <sub>DD</sub>	Supply voltage pin	32	VM11	Motor supply voltage pin 1

## ■ Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage <sup>*2</sup>	V <sub>DD</sub>	6.5	V
	V <sub>M11, 12</sub>		
	V <sub>M21, 22</sub>		
Drive output voltage <sup>*5</sup>	V <sub>(m)</sub>	15	V
Control signal input voltage <sup>*6</sup>	V <sub>(n)</sub>	0 to V <sub>DD</sub>	V
Supply current	I <sub>DD</sub>	30	mA
Drive output current <sup>*4</sup>	I <sub>(o)</sub>	±1 200	mA
Hall bias current <sup>*7</sup>	I <sub>HB(n)</sub>	30	mA
Power dissipation <sup>*3</sup>	P <sub>D</sub>	293	mW
Operating ambient temperature <sup>*1</sup>	T <sub>opr</sub>	-30 to +85	°C
Storage temperature <sup>*1</sup>	T <sub>stg</sub>	-55 to +150	°C

Note) Do not apply external currents or voltages to any pins not specifically mentioned.

For circuit currents, '+' denotes current flowing into the IC, and '-' denotes current flowing out of the IC.

\*1: Except for the operating ambient temperature and storage temperature, all ratings are for T<sub>a</sub> = 25°C.

\*2: The voltage in the step-up voltage circuit exceeds the supply voltage.

For the allowable value of the step-up voltage, refer to "■ Electrical Characteristics".

\*3: The power dissipation shown is the value of independent IC without a heat sink at T<sub>a</sub> = 70°C. Refer to the P<sub>D</sub> — T<sub>a</sub> curves of the "■ Application Notes" for details.

\*4: o = 17, 18, 21, 22, 23, 24, 25, 26, 27, 28, 31, 32

\*5: m = 21, 22, 24, 25, 27, 28

\*6: n = 2, 3, 4, 5, 6, 7, 8, 9, 11, 30

\*7: n = 1

## ■ Recommended Operating Range

Parameter	Symbol	Range	Unit
Supply voltage	V <sub>DD</sub>	4.5 to 5.5	V
	V <sub>M11, 12</sub>		
	V <sub>M21, 22</sub>		

## ■ Electrical Characteristics at T<sub>a</sub> = 25°C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Overall</b>						
Circuit current 1	I <sub>DD1</sub>	V <sub>DD</sub> = 5 V in power save mode	—	0	0.2	mA
Circuit current 2	I <sub>DD2</sub>	V <sub>DD</sub> = 5 V including step-up circuit	—	7	14	mA
<b>Start/stop</b>						
Start voltage	V <sub>START</sub>	Voltage with which a circuit operates at V <sub>DD</sub> = 5 V and L → H	2.7	—	—	V
Stop voltage	V <sub>STOP</sub>	Voltage with which a circuit becomes off at V <sub>DD</sub> = 5 V and H → L	—	—	0.7	V
<b>Hall bias</b>						
Hall bias voltage	V <sub>HB</sub>	V <sub>DD</sub> = 5 V, I <sub>HB</sub> = 20 mA	0.7	1.2	1.6	V
<b>Hall amplifier</b>						
Input bias current	I <sub>BH</sub>	V <sub>DD</sub> = 5 V	—	1	5	μA
In-phase input voltage range	V <sub>HBR</sub>	V <sub>DD</sub> = 5 V, except for H2H, H2L	1.5	—	4.0	V
Minimum input level	V <sub>INH</sub>	V <sub>DD</sub> = 5 V	60	—	—	mV[p-p]
<b>Torque command</b>						
In-phase input voltage range	EC	V <sub>DD</sub> = 5 V	0.5	—	3.9	V
Offset voltage	EC <sub>OF</sub>	V <sub>DD</sub> = 5 V	-100	0	100	mV
Dead zone	EC <sub>DZ</sub>	V <sub>DD</sub> = 5 V	0	75	150	mV
Input current	EC <sub>IN</sub>	V <sub>DD</sub> = 5 V, EC = ECR = 2.5 V	-5	-1	—	μA
Input/output gain	A <sub>CS</sub>	V <sub>DD</sub> = 5 V, R <sub>CS</sub> = 0.33 Ω	0.36	0.48	0.60	A/V
<b>Output</b>						
High-level output saturation voltage	V <sub>OH</sub>	V <sub>DD</sub> = 5 V, I <sub>O</sub> = -500 mA	—	0.15	0.30	V
Low-level output saturation voltage	V <sub>OL</sub>	V <sub>DD</sub> = 5 V, I <sub>O</sub> = 500 mA	—	0.15	0.30	V
Torque limit current	I <sub>TL</sub>	V <sub>DD</sub> = 5 V, R <sub>CS</sub> = 0.33 Ω	455	570	685	mA
<b>FG</b>						
FG output high-level	FG <sub>H</sub>	V <sub>DD</sub> = 5 V, I <sub>FG</sub> = -0.01 mA	3	—	—	V
FG output low-level	FG <sub>L</sub>	V <sub>DD</sub> = 5 V, I <sub>FG</sub> = 0.01 mA	—	—	0.5	V
In-phase input voltage range	V <sub>FGR</sub>	V <sub>DD</sub> = 5 V	1.5	—	3.0	V
FG hysteresis width	H <sub>FG</sub>	V <sub>DD</sub> = 5 V	5	10	20	mV
<b>Step-up circuit</b>						
Step-up voltage	V <sub>PUMP</sub>	V <sub>DD</sub> = 5 V	7	—	10	V

## ■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>PWM oscillation changeover</b>						
Input high-level	$\text{PWM}_H$	$V_{DD} = 5 \text{ V}$	4.5	—	—	V
Input low-level	$\text{PWM}_L$	$V_{DD} = 5 \text{ V}$	—	—	0.5	V

### • Design reference data

Note) The characteristics listed below are theoretical values based on the IC design and are not guaranteed.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>PWM oscillation changeover</b>						
PWM frequency high-level	$f_{\text{PWMH}}$	$V_{DD} = 5 \text{ V}$ , PWMSW = Low	—	80	—	kHz
PWM frequency low-level	$f_{\text{PWML}}$	$V_{DD} = 5 \text{ V}$ , PWMSW = High	—	40	—	kHz

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>Thermal protection</b>						
Thermal protection operating temperature	$T_{SDON}$	$V_{DD} = 5 \text{ V}$	—	150	—	°C
Thermal protection hysteresis width	$\Delta T_{SD}$	$V_{DD} = 5 \text{ V}$	—	40	—	°C

## ■ Usage Notes

- Prevent this IC from being line-to-ground fault.

(To be concrete, do not short-circuit any of A31 (pin 21), A32 (pin 22), A21 (pin 24), A22 (pin 25), A11 (pin 27) and A12 (pin 28) with GND pin (pin 15).)

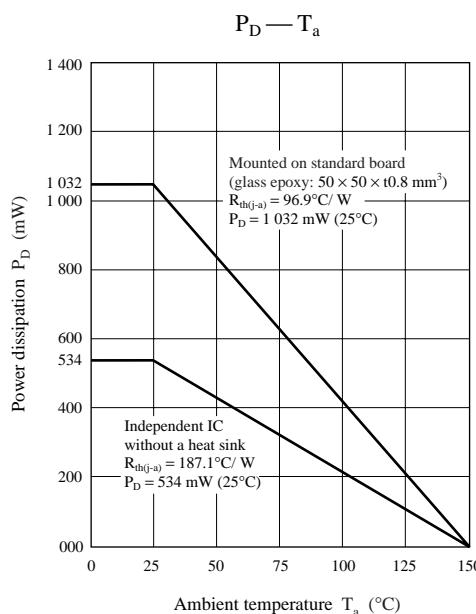
- Be careful of the following three pins because their static breakdown voltages are low. ( $C = 200 \text{ pF}$ ,  $R = 0 \Omega$ )

Pin 23: breakdown at 120 V

Pin 26: breakdown at 120 V

## ■ Application Notes

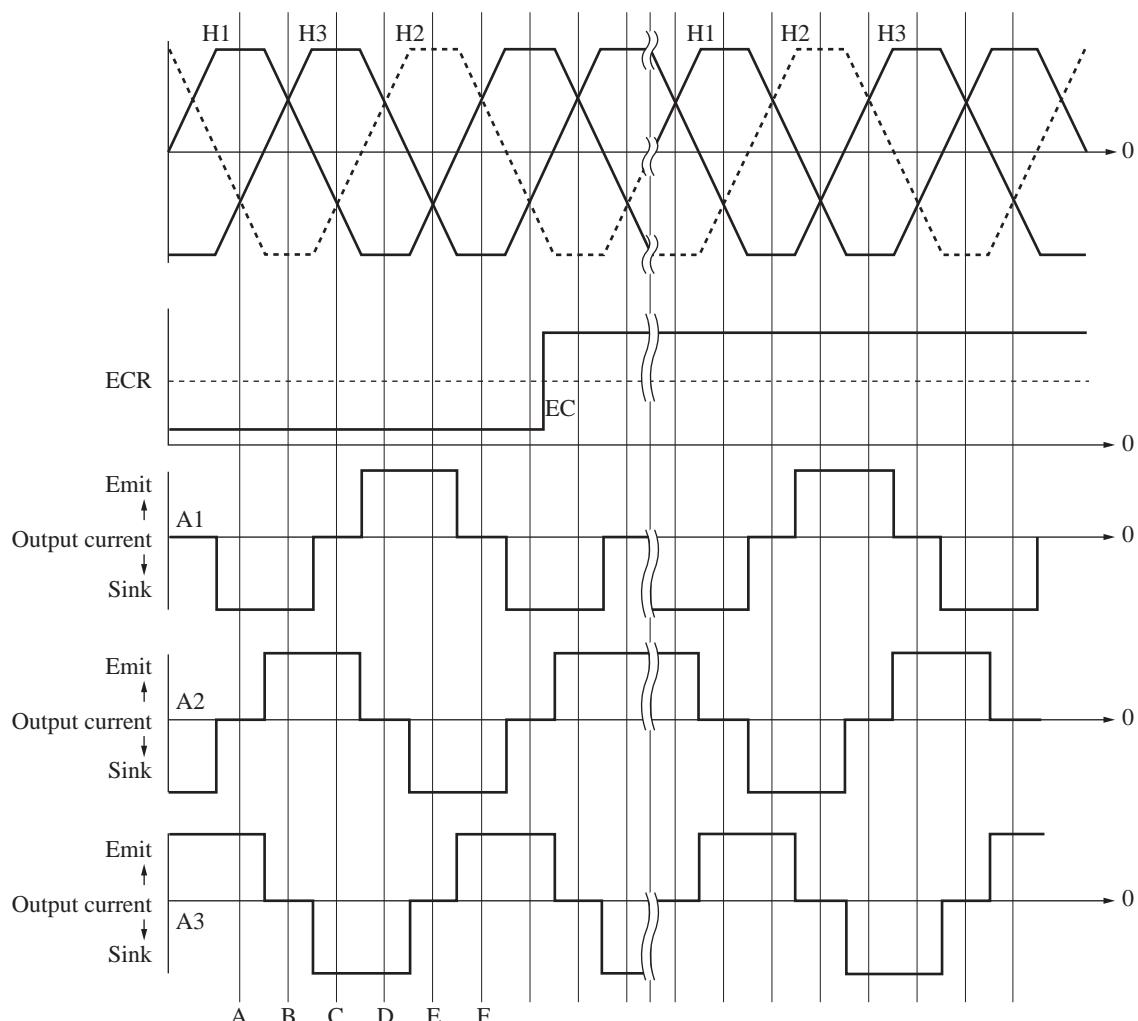
- $P_D - T_a$  curves of SSOP032-P-0300



## ■ Application Notes (continued)

- Phase conditions between Hall input and output current

	Phase of Hall pin		
	H1H	H2H	H3H
A	H	ML	ML
B	MH	L	MH
C	ML	ML	H
D	L	MH	MH
E	ML	H	ML
F	MH	MH	L



## ■ Application Circuit Example

(Check the stipulated value of electrical characteristics  
and then determine resistance value.)

